

V1.1 Datasheet

P-Channel -40V MOSFET

FEATURES

- Trench Process Technology
- ●Ultra Low On-resistance Design

PRODUCTY SUMMARY								
V _{DS}	I_D	$R_{DS(on)}(m\Omega)$ Max						
40	-120	3.1	@V _{GS} =	10	V			
-40	-120	3.8	@V _{GS} =	4.5	V			

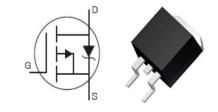
Application

- ●BMS Application
- ●Consumer Electronics
- ●DC/DC Converters

Mechanical

●Case:TO-263 Package

TO-263



Packing Information

Package	Packing		
TO-263	800EA/13" Reel		

Maximum Ratings (T _A =25°C unless otherwise specified)								
Param	neter	Symbol	Limit	Unit				
Drain-Source Voltage		V _{DS}	-40	V				
Gate-Source Voltage		V_{GS}	±25	V				
Continuous Drain Course t 2)	$T_{C}=25^{\circ}C, V_{GS}=-10V$	ı	-120					
Continuous Drain Current 2)	$T_C=25^{\circ}C$, $V_{GS}=-10V$ $T_C=100^{\circ}C$, $V_{GS}=-10V^{3)}$		-114	A				
Pulsed Drain Current 1)	T _C =25°C	I _{DM.pulesd}	-480	А				
Avalanche Current		I _{AS}	-120	А				
Avalanche Energy	I _D =-60A	E _{AS}	60	mJ				
Power Dissipation	P_{D}	136	W					
Operating Junction and Storage	T _J , T _{STG}	-55 to 175	°C					

Typical Thermal Resistance							
Parameter Symbol Limit Unit							
Junction-to-Ambient Thermal Resistance 5)	$R_{\theta JA}$	62	°C/W				
Junction-to-Case Thermal Resistance	$R_{ heta JC}$	1.1	°C/W				

- 1. Pulse width<300us, Duty cycle<2%.
- 2. Fused current that based on wire numbers and diameter.
- Guaranteed by design, not subject to production testing.
 The maximum current rating is package limited.
- 5. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keepinitial T_J =25°C.



Electrical Characteristics (T _A = 25°C UNLESS OTHERWISE NOTED)							
Characteristics	Symbol	Test Condition	Limits			l lmit	
Gilal acteristics			Min	Тур	Max	Unit	
Static							
Drain-Source Breakdown Voltage	B _{VDSS}	V_{GS} =0V, I_D =-250uA	-40	ı	ı	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-1.0	-1.6	-2.5	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10.0V, I _D =-95A	-	-	3.1	mΩ	
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =-4.5V, I_{D} =-75A	-	-	3.8	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V	-	-	-1.0	μΑ	
GateSource Leakage Current	I _{GSS}	V_{GS} =±25V, V_{DS} =0V	-	-	±100	nA	

Dynamic ³⁾							
Total Gate Charge	Q_g	V _{DS} =-20V,	1	369	1		
Gate-Source Charge	Q_{gs}	V _{GS} =-10V, I _D =-120A	ı	30	ı	nC	
Gate-Drain Charge	Q_{gd}		-	72	-		
Input Capacitance	C _{iss}		-	19678	1		
Output Capacitance	C _{oss}	V_{DS} =-20V, V_{GS} =0V, f=1MHz	-	1254	-	pF	
Reverse Transfer Capacitance	C_{rss}		-	1270	-		

Switching							
Turn-On Delay Time	$t_{d(on)}$		-	52	-		
Turn-On Rise Time	t _r	V _{DS} =-20V, V _{GS} =-10V,	-	47	-	20	
Turn-Off Delay Time	t _{d(off)}	Rg=3.0Ω, I _D =-120A	-	418	-	ns	
Turn-Off Fall Time	t _f		-	118	-		

Drain-Source Diode							
Maximum Continuous Body Diode Forward Current	I _S	T _C =25°C	1	-	-120	А	
Diode Forward Voltage	V_{SD}	I _F =-95A, V _{GS} =0V, T _C =25°C	-	-0.66	-1	V	
Reverse Recovery Time	t _{rr}	V _R =-20V, I _F =-50A,	-	54	-	nS	
Reverse Recovery Charge	Q _{rr}	d <i>i_F</i> /d <i>t</i> =100A/μS	-	60	-	nC	

Note:

- Note:

 1. Pulse width<300us, Duty cycle<2%.

 2. Essentially independent of operating temperature typical characteristics.

 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.

 4. The maximum current rating is package limited.

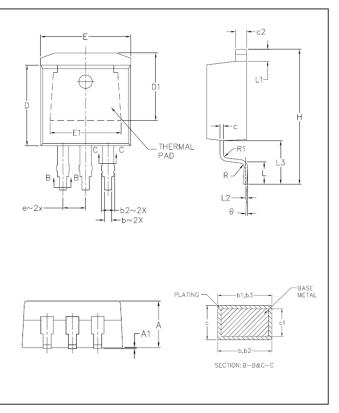
 5. R_{QJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch2 with 2oz.square pad of copper.

 6. Guaranteed by design, not subject to production testing.

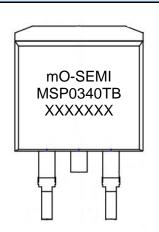


Package Outline Dimensions (inches and millimeters)

TO-263								
	Dimensions							
SYMBOL	Millin	neters	Inches					
	Min	Max	Min	Max				
Α	4.064	4.826	0.160	0.190				
A1	0.000	0.254	0.000	0.010				
b	0.508	0.991	0.020	0.039				
b1	0.508	0.889	0.020	0.035				
b2	1.143	1.778	0.045	0.070				
b3	1.143	1.727	0.045	0.068				
С	0.381	0.737	0.015	0.029				
c1	0.381	0.584	0.015	0.023				
c2	1.143	1.651	0.045	0.065				
D	8.382	9.652	0.330	0.380				
D1	6.858	-	0.270	-				
E	9.652	10.668	0.380	0.420				
E1	6.223	-	0.245	-				
е	2.54	BSC	0.10BSC					
Н	14.605	15.875	0.575	0.625				
L	1.778	2.790	0.070	0.110				
L1	-	1.676	-	0.066				
L2	0.254BSC		0.010BSC					
L3	4.780	5.280	0.188	0.208				
R	0.460	TYP	0.018 TYP					
R1	0.460) TYP	0.018 TYP					
θ	0°	8°	0°	8°				



Marking Information



mO-SEMI =Series Name

MSP0340 =Part Number Marking Code

XXXXXXX =Product Tracking Code

*TB=TO-263 =Single TO-263

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